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High voltage fast switching NPN power transistor

Datasheet — production data

Features

- High voltage capability
- Fast switching speed

Applications

- Lighting
- Switch mode power supply

Description

This device is a high voltage fast-switching NPN power transistor. It is manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA. The device is designed for use in lighting applications and low cost switch-mode power supplies.

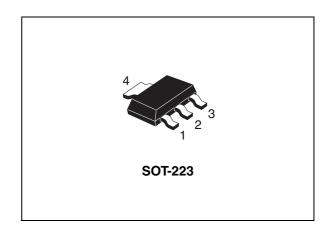


Figure 1. Internal schematic diagram

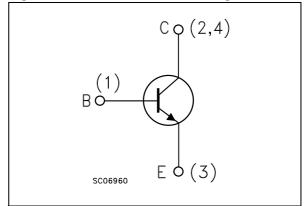


Table 1. Device summary

Order codes	Marking	Package	Packaging	
STN2580	N2580	SOT-223	Tape and reel	

Contents STN2580

Contents

1	Electrical ratings	. 3
2	Electrical characteristics	. 4
	2.1 Electrical characteristics (curves)	. 5
3	Test circuit	. 8
4	Package mechanical data	. 9
5	Packaging mechanical data	11
6	Revision history	13

STN2580 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage (V _{BE} = 0)	800	V
V_{CEO}	Collector-emitter voltage (I _B = 0)	400	٧
V _{EBO}	Emitter-base voltage (I _C = 0)	9	V
I _C	Collector current	1	Α
I _{CM}	Collector peak current (t _P < 5 ms)	2	Α
Ι _Β	I _B Base current		Α
P _{TOT}	Total dissipation at T _{amb} = 25 °C	1.6	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

	Symbol	Parameter	Value	Unit
ĺ	R_{thJA}	Thermal resistance junction-ambient max ⁽¹⁾	78	°C/W

^{1.} When mounted on PCB area of 1cm²

Electrical characteristics STN2580

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

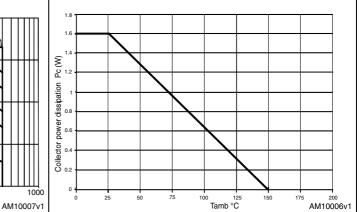
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 800 V			10	μА
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 8 V			100	μΑ
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA	400			V
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	I _E = 100 μA	9			V
h _{FE} (1)	DC current gain	$I_C = 250 \text{ mA}$ $V_{CE} = 5 \text{ V}$	60	100		
V _{CE(sat)} (1)	Collector-emitter saturation voltage	I _C = 1 A I _B = 0.2 A			1	V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 1 A I _B = 0.2 A			1.1	V
	Resistive load					
t _r	Rise time	V_{CC} =200 V, I_{C} =0.3 A		140		ns
t _s	Storage time	I _{B1} =20 mA, I _{B2} =-50 mA		4		μs
t _f	Fall time	T _p =30 μs		90		ns

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2%

Electrical characteristics (curves) 2.1

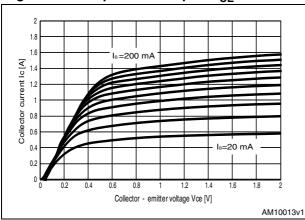
Figure 2. Safe operating area

Figure 3. **Derating curve**



Output curves up to $V_{CE}=2 V$ Figure 4.

Vce [V]



Output curves up to $V_{CE}=10~V$ Figure 5.

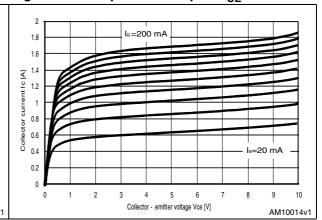


Figure 6. DC current gain $(V_{CE} = 1 V)$

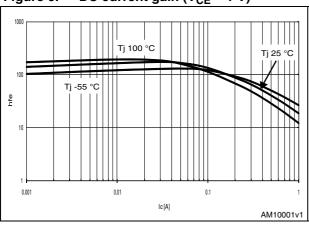
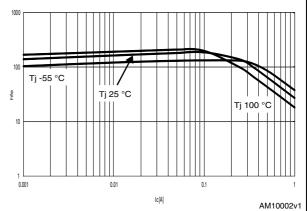


Figure 7. DC current gain $(V_{CE} = 5 V)$



Electrical characteristics STN2580

Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage

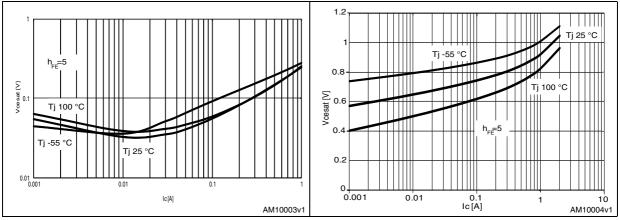


Figure 10. Base-emitter on voltage

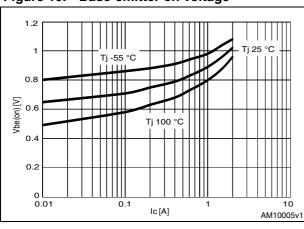


Figure 11. Capacitance variation

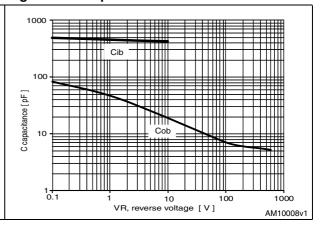


Figure 12. Resistive switching time

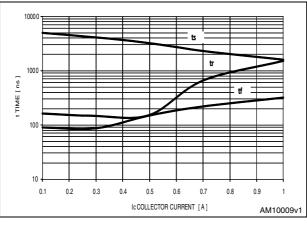


Figure 13. V_{be(sat)} vs. I_C

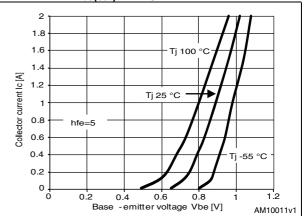
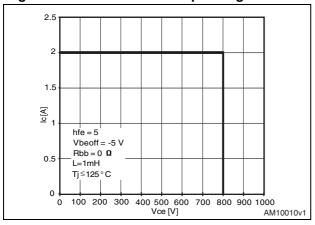


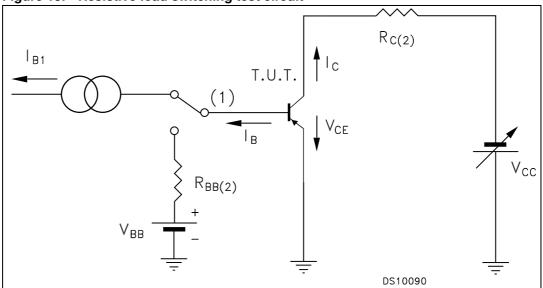
Figure 14. Reverse biased operating area



Test circuit STN2580

3 Test circuit

Figure 15. Resistive load switching test circuit



- 1. Fast electronic switching
- 2. Non-inductive resistor

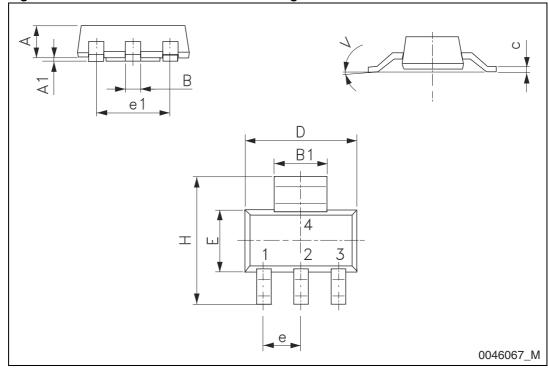
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. SOT-223 mechanical data

Dim.	mm				
Dilli.	Min.	Тур.	Max.		
Α			1.80		
A1	0.02		0.1		
В	0.60	0.70	0.85		
B1	2.90	3.00	3.15		
С	0.24	0.26	0.35		
D	6.30	6.50	6.70		
е		2.30			
e1		4.60			
E	3.30	3.50	3.70		
Н	6.70	7.00	7.30		
V			10°		

Figure 16. SOT-223 mechanical data drawing



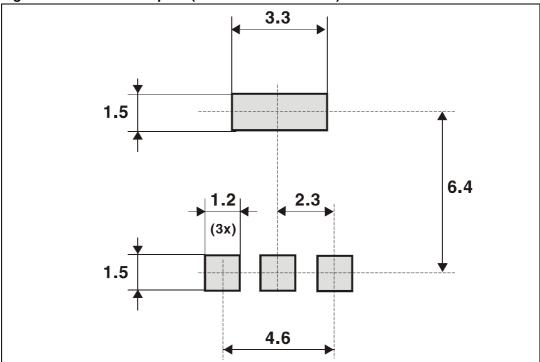


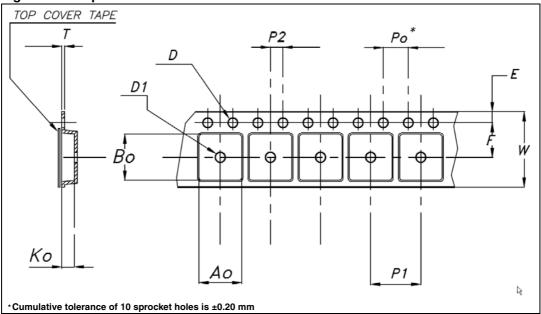
Figure 17. SOT-223 footprint (dimensions are in mm)

5 Packaging mechanical data

Table 6. SOT-223 tape and reel mechanical data

Таре				Reel		
Dim.	mm		Dim.	mm		
DIM.	Min.	Тур.	Max.	Dim.	Min.	Max.
A0	6.75	6.85	6.95	Α		180
В0	7.30	7.40	7.50	N	60	
K0	1.80	1.90	2.00	W1		12.4
F	5.40	5.50	5.60	W2		18.4
Е	1.65	1.75	1.85	W3	11.9	15.4
W	11.7	12	12.3			
P2	1.90	2	2.10	Base qu	antity pcs	1000
P0	3.90	4	4.10	Bulk qua	antity pcs	1000
P1	7.90	8	8.10			
Т	0.25	0.30	0.35			
Dφ	1.50	1.55	1.60			
D1¢	1.50	1.60	1.70			

Figure 18. Tape for SOT-223



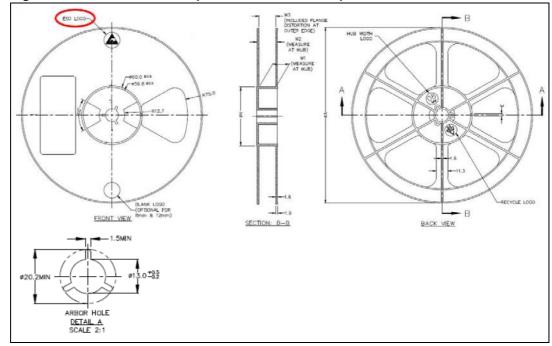


Figure 19. Reel for SOT-223 (dimensions are in mm)

Revision history STN2580

6 Revision history

Table 7. Document revision history

Date	Revision	Changes	
30-Oct-2012	1	Initial release.	
10-Jan-2013	2	Added new section: Packaging mechanical data	

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